

1200 V, 20 A SiC Schottky diode in D2PAK R2P for automotive applications

28 July 2025

**Product data sheet** 

## 1. General description

Nexperia introduces leading edge Silicon Carbide (SiC) Schottky diode for ultra high performance, low loss, high efficiency power conversion applications. The SiC Schottky diode encapsulated in a Real-2-Pin D2PAK R2P (TO-263-2) Surface-Mounted Device (SMD) power plastic package offers temperature independent capacitive turn-off, zero recovery switching behavior combined with an outstanding figure-of-merit ( $Q_C \times V_F$ ). The Merged PiN Schottky (MPS) diode improves the robustness expressed in a high  $I_{FSM}$ .

### 2. Features and benefits

- · Reduced system costs
- Temperature independent fast and smooth switching performance
- Outstanding figure of merit (Q<sub>c</sub> x V<sub>F</sub>)
- High I<sub>FSM</sub> capability
- · High power density
- System miniaturization
- Reduced EMI
- Qualified according to AEC-Q101 and recommended for use in automotive applications

## 3. Applications

- Traction inverter
- DC-DC converter
- · Onboard charger

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>F</sub>	forward current	T <sub>c</sub> ≤ 135 °C; δ = 1	-	-	20	Α
Static characte	eristics					
$V_{DC}$	DC blocking voltage	T <sub>j</sub> = 25 °C	1200	-	-	V
Dynamic chara	cteristics			•		
Q <sub>C</sub>	total capacitive charge	$V_R = 800 \text{ V}; \text{ dI}_F/\text{dt} = 200 \text{ A/}\mu\text{s}; \text{ I}_F = 20 \text{ A}; $ $T_j = 25 ^{\circ}\text{C}$	-	85	-	nC



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# 5. Pinning information

**Table 2. Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	mb	
2	Α	anode		
mb	K	mounting base; connected to cathode	D2PAK R2P (SOT8018)	K K; mb

# 6. Ordering information

**Table 3. Ordering information** 

Type number			
	Name	Description	Version
PSC20120J-Q	D2PAK R2P	Plastic, single-ended surface-mounted package (D2PAK R2P); Real-2-Pin configuration; 5.08 mm pitch; 8.8 mm x 10.35 mm x 4.46 mm body	SOT8018

# 7. Marking

### Table 4. Marking codes

Type number	Marking code
PSC20120J-Q	PSC20120Q

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# 8. Limiting values

### **Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	N	Min	Max	Unit
$V_{RRM}$	repetitive peak reverse voltage	T <sub>j</sub> = 25 °C	-		1200	V
l <sub>F</sub>	forward current	T <sub>c</sub> ≤ 135 °C; δ = 1	-		20	Α
I <sub>FSM</sub>	non-repetitive peak	t <sub>p</sub> = 10 μs; square wave; T <sub>c</sub> = 25 °C	-		710	Α
	forward current	t <sub>p</sub> = 10 ms; half sine-wave; T <sub>c</sub> = 25 °C	-		135	Α
		t <sub>p</sub> = 10 ms; half sine-wave; T <sub>c</sub> = 150 °C	-		100	Α
∫i <sup>2</sup> dt	i <sup>2</sup> t value	t <sub>p</sub> = 10 ms; T <sub>c</sub> = 25 °C	-		91	A²s
		$t_p$ = 10 ms; $T_c$ = 150 °C	-		50	A²s
P <sub>tot</sub>	total power dissipation	T <sub>c</sub> ≤ 25 °C	-		200	W
Tj	junction temperature		-:	55	175	°C
T <sub>amb</sub>	ambient temperature		-:	55	175	°C
T <sub>stg</sub>	storage temperature		-(	65	175	°C

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## 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-c)</sub>	thermal resistance from junction to case		-	0.6	0.75	K/W

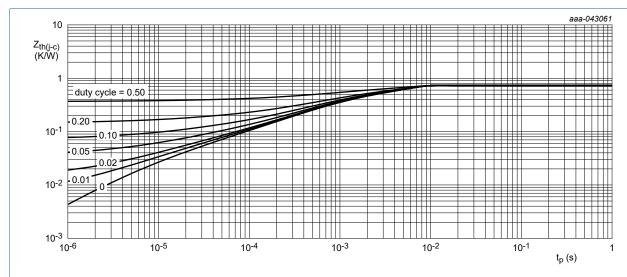


Fig. 1. Transient thermal impedance as a function of pulse duration; maximum values

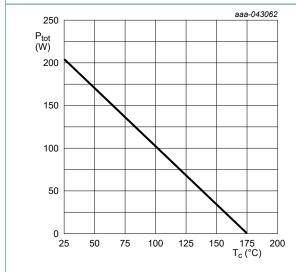


Fig. 2. Power dissipation; maximum values

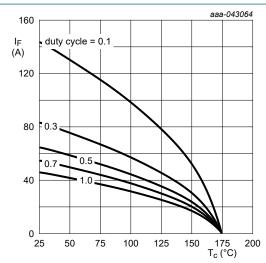


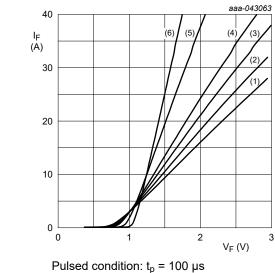
Fig. 3. Forward current as a function of case temperature; maximum values

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# 10. Characteristics

**Table 7. Characteristics** 

Symbol	Parameter	Conditions	I	Min	Тур	Max	Unit
Static char	acteristics					•	
$V_{DC}$	DC blocking voltage	T <sub>j</sub> = 25 °C		1200	-	-	V
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 20 A; T <sub>j</sub> = 25 °C	-	-	1.5	1.8	V
		I <sub>F</sub> = 20 A; T <sub>j</sub> = 150 °C	-	-	2.2	2.6	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 1200 V; T <sub>j</sub> = 25 °C	-	-	1	180	μΑ
		V <sub>R</sub> = 1200 V; T <sub>j</sub> = 150 °C	-	-	10	500	μΑ
Dynamic c	haracteristics				·	•	
C <sub>d</sub>	diode capacitance	V <sub>R</sub> = 1 V; f = 1 MHz; T <sub>j</sub> = 25 °C	-	-	1150	-	pF
		V <sub>R</sub> = 800 V; f = 1 MHz; T <sub>j</sub> = 25 °C	-	-	70	-	pF
Q <sub>C</sub>	total capacitive charge	$V_R = 800 \text{ V}; \text{ dI}_F/\text{dt} = 200 \text{ A/}\mu\text{s}; \text{ I}_F = 20 \text{ A}; $ $T_j = 25 ^{\circ}\text{C}$	-	-	85	-	nC





(1) 
$$T_j = 175 \,^{\circ}C$$

$$(2) T_i = 150 ° ($$

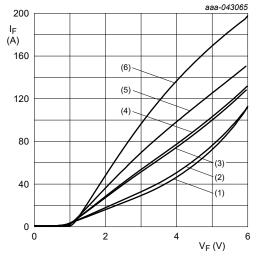
(2) 
$$T_j = 150 \,^{\circ}\text{C}$$
  
(3)  $T_j = 125 \,^{\circ}\text{C}$ 

$$(4) T_j = 100 °C$$

$$(5) T_i = 25 °C$$

(6) 
$$T_i = -55 \,^{\circ}\text{C}$$

Forward current as a function of forward Fig. 4. voltage; typical values



Pulsed condition:  $t_p = 100 \mu s$ 

(1) 
$$T_j = 175 \,^{\circ}\text{C}$$

(2) 
$$T_j = 150 \,^{\circ}\text{C}$$
  
(3)  $T_j = 125 \,^{\circ}\text{C}$ 

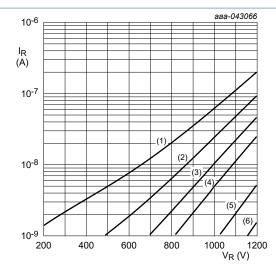
$$(4) T_j = 100 °C$$

$$(5) T_i = 25 °C$$

(6) 
$$T_i = -55 \,^{\circ}\text{C}$$

Fig. 5. Forward characteristics in surge current as a function of forward voltage; typical values

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Pulsed condition:

(1)  $T_i = 175 \, ^{\circ}C$ 

 $(2) T_i = 150 °C$ 

 $(3) T_i = 125 °C$ 

 $(4) T_j = 100 °C$ 

(5)  $T_j = 25 ^{\circ}C$ (6)  $T_j = -55 ^{\circ}C$ 

Fig. 6. Reverse current as a function of reverse voltage; typical values

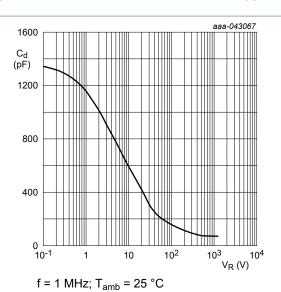


Fig. 7. Diode capacitance as a function of reverse voltage; typical values

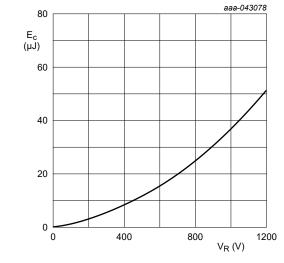


Fig. 8. Capacitance stored energy as a function of reverse voltage; typical values

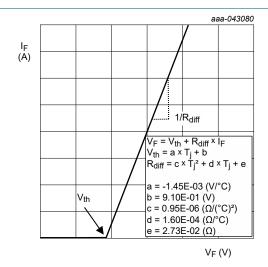
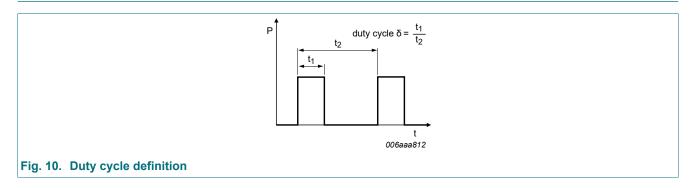


Fig. 9. Simplified forward characteristics mode

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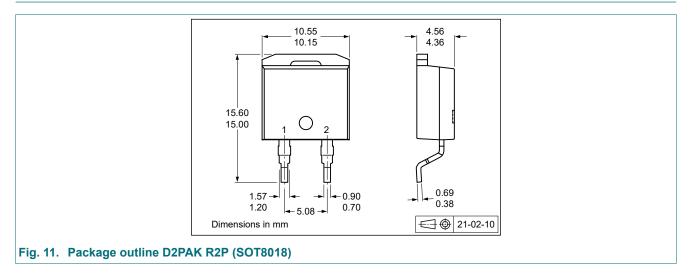
# 11. Test information



## **Quality information**

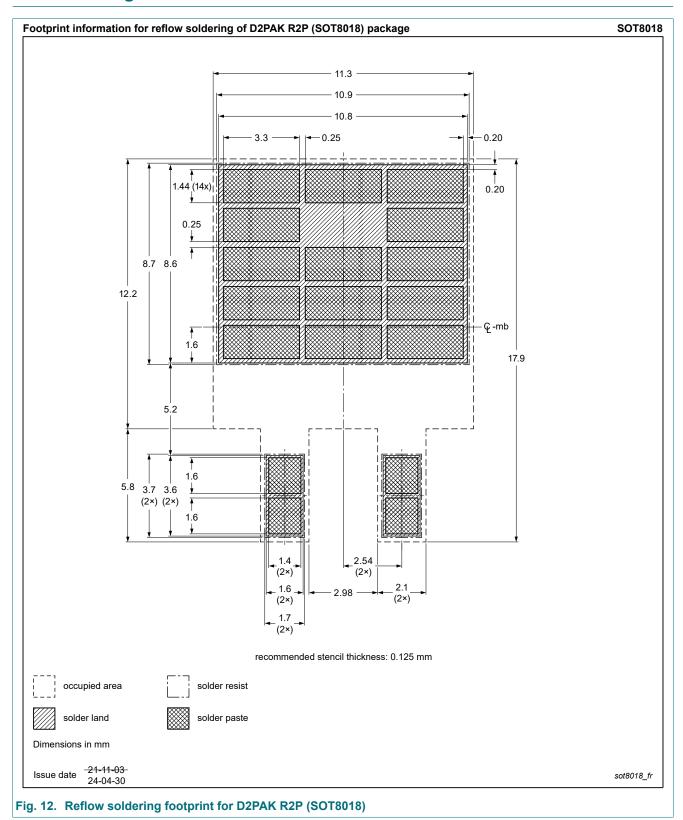
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

# 12. Package outline



### 1200 V, 20 A SiC Schottky diode in D2PAK R2P for automotive applications

# 13. Soldering



## 1200 V, 20 A SiC Schottky diode in D2PAK R2P for automotive applications

# 14. Revision history

### **Table 8. Revision history**

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PSC20120J-Q v.1	20250728	Product data sheet	-	-

#### 1200 V, 20 A SiC Schottky diode in D2PAK R2P for automotive applications

## 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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PSC20120J-Q

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